Patent - ZH oz Attorney's Docket No. 015290-440

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of)			
Rajinder Dhindsa et al.) Group Art Unit: 2813			
Application No.: 09/689,845) Examiner: K. Christianson			
Filed:	October 13, 2000))) I hereby certify	that this corres	pondence is bein	a sent
For:	STEPPED UPPER ELECTRODE FOR PLASMA PROCESSING UNIFORMITY) by Facsin) Commissioner	nile Transmissio	on to the Assistant ashington, D.C. 2	ť
	SUPPLEMENTA	Date: Name:	Cauca Signatura	BOUT	
			certificate		18
Assistant Commissioner for Patents Washington, D.C. 20231		Sign: Signature	of person sign	Ing the certificate)	
Sir:	•	Date:	(Date of Sign	o Z	
	Further to the Amendment filed Decem	ber 18, 2001, ple	ase amend the	application	
as follows.			FAX: COM	PY RECEIVED	

IN THE CLAIMS:

JAN 17 2002

TECHNOLOGY CENTER 2800 Please cancel Claims 13 and 20 without prejudice or disclaimer of the subject matter

thereof and replace Claims 12 and 19 as follows:

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12. (Amended) A method of treating a semiconductor substrate in a plasma chamber, said method comprising the steps of:

supporting the semiconductor substrate on a bottom electrode;

supplying process gas to the chamber;

forming a plasma adjacent an exposed surface of an upper electrode; and

processing the semiconductor substrate with the plasma;